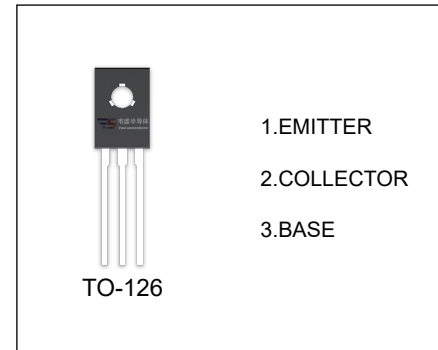


## 2SB776 TRANSISTOR (PNP)

### FEATURES

- High Current Output Up to 3A
- Low Saturation Voltage Power Dissipation



### ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
2SB776	TO-126	Bulk	200pcs/Bag
2SB776-TU	TO-126	Tube	60pcs/Tube

### MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted )

Symbol	Parameter	Value	Unit
V <sub>CB0</sub>	Collector-Base Voltage	-50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-50	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current –Continuous	-3	A
P <sub>C</sub>	Collector Power Dissipation	1	W
T <sub>J</sub> , T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55-150	°C

**$T_a=25\text{ }^\circ\text{C}$  unless otherwise specified**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
<b>Collector-base breakdown voltage</b>	$V_{(BR)CBO}$	$I_C=-100\mu\text{A}, I_E=0$	-50			V
<b>Collector-emitter breakdown voltage</b>	$V_{(BR)CEO}$	$I_C=-5\text{mA}, I_B=0$	-50			V
<b>Emitter-base breakdown voltage</b>	$V_{(BR)EBO}$	$I_E=-100\mu\text{A}, I_C=0$	-5			V
<b>Collector cut-off current</b>	$I_{CBO}$	$V_{CB}=-50\text{V}, I_E=0$			-1	$\mu\text{A}$
<b>Emitter cut-off current</b>	$I_{EBO}$	$V_{EB}=-3\text{V}, I_C=0$			-1	$\mu\text{A}$
<b>DC current gain</b>	$h_{FE(1)}$	$V_{CE}=-2\text{V}, I_C=-20\text{mA}$	100			
	$h_{FE(2)}$	$V_{CE}=-2\text{V}, I_C=-1\text{A}$	100		400	
<b>Collector-emitter saturation voltage</b>	$V_{CE(sat)}$	$I_C=-2\text{A}, I_B=-200\text{mA}$			-0.5	V
<b>Base-emitter saturation voltage</b>	$V_{BE(sat)}$	$I_C=-2\text{A}, I_B=-200\text{mA}$			-2	V
<b>Transition frequency</b>	$f_T$	$V_{CE}=-5\text{V}, I_C=-100\text{mA}$		80		MHz
<b>Collector output capacitance</b>	$C_{ob}$	$V_{CB}=-10\text{V}, I_E=0, f=1\text{MHz}$		45		pF